Bi-CMOS Linear Integrated Circuit Silicon Monolithic

TB2938HQ

Maximum Power 49W BTL \times 4-ch Audio Power IC

1. Description

The TB2938HQ is a four-channel BTL power amplifier for car audio applications.

This IC has a pure complementary P-ch and N-ch DMOS output stage, offering maximum output power (POUT MAX) of 49W.

It includes a standby switch, mute function and various protection features.



Weight: 7.7 g (typ.)

2. Applications

Power IC developed for car audio applications.

3. Features

- High output power, low distortion, and low noise property (for details, refer to the Table 3-1)
- Built-in various detection function (Output DC offset detection, Output short, Output layer short) (pin25)
- Built-in various mute functions (low voltage, standby on/off) (pin22)
- Built-in standby switch (pin4)
- Built-in mute switch (pin22)
- Start stop Cruising corresponded (at Vcc=6V)
- Built-in various protection circuits (thermal shut down, over-voltage, short to GND, short to VCC, and output to output short, speaker current limiting)

Table 3-1 Typical Characteristics

(Note1,Note2)

Condition	Тур.	Unit					
Output power (P _{OUT})							
V _{CC} = 15.2 V, JEITA max	49						
V _{CC} = 14.4 V, JEITA max	JEITA max 44 v						
V _{CC} = 14.4 V, THD = 10%	29	vv					
THD = 10%	24						
Total harmonic distortion (THD)							
P _{OUT} = 5 W	0.01	%					
Output noise voltage (V _{NO}) (Rg = 0 Ω),							
BW = 20 Hz to 20 kHz	50	μV					
Operating Supply voltage range (V_{CC})							
RL = 4 Ω	6 to 18	V					

Note1: Typical test conditions: V_{CC} = 13.2 V, f = 1 kHz, R_L = 4 Ω , G_V = 26 dB, Ta = 25°C; unless otherwise specified. Note2: Rg: signal source resistance

4. Block Diagram



Some of the functional blocks, circuits or constants may be omitted from the block diagram or simplified for explanatory purposes. In the following explanation, a "channel" is a circuit which consists of INx, OUTx (+), OUTx (-), and PW-GNDx. (x:1 to 4)

- 5. Pin Configuration and Function Descriptions
- 5.1 Pin Configuration (top view)



5.2 Pin Function Descriptions

Pin	Symbol	I/O (Note3)	Description
1	TAB	—	TAB (Always connect with GND)
2	PW-GND2	—	Ground for Rear Left output
3	OUT2(-)	OUT	Rear Left output-
4	Stby	V _{ST} -IN	Standby voltage input
5	OUT2(+)	OUT	Rear Left output+
6	V _{CC2}	V _{CC} -IN	Supply voltage 2
7	OUT1(-)	OUT	Front Left output-
8	PW-GND1	_	Ground for Front Left output
9	OUT1(+)	OUT	Front Left output+
10	Ripple	—	Ripple voltage
11	IN1	IN	Front Left input
12	IN2	IN	Rear Left input
13	Pre-GND	_	Signal ground
14	IN4	IN	Rear Right input
15	IN3	IN	Front Right input
16	AC-GND	_	Common reference voltage for all input
17	OUT3(+)	OUT	Front Right output+
18	PW-GND3	_	Ground for Front Right output
19	OUT3(-)	OUT	Front Right output-
20	V _{CC1}	V _{CC} -IN	Supply voltage 1
21	OUT4(+)	OUT	Rear Right output+
22	Mute	V _{mute} IN	Mute voltage input
23	OUT4(-)	OUT	Rear Right output-
24	PW-GND4	_	Ground for Rear Right output
25	Det	(OC)	DCoffset/Short/Layershort output det

Note3: (OC) means (Open Collector).

6. Detailed Description

6.1 External Component Constants



Component	Recommende			Effect (Note4)			
Name	d Value	Pin	Purpose	Lower than Recommended Value	Higher than Recommended Value		
C1	0.22 μF	INx(x:1to4)	To eliminate DC	Cut-off frequency becomes higher	Cut-off frequency becomes lower		
C2	10 μF(Note5)	Ripple	To reduce ripple	Turn on/off time and turn-on diag. cycle shorter	Turn on/off time and turn-on diag. cycle longer		
C3	0.1 μF	$V_{CC1, V_{CC2}}$	To provide sufficient oscillation margin	Reduces noise and provides sufficient oscillation margin			
C4	1uF	Mute	To reduce pop noise	High pop noise. Duration until mute function is turned on/off is short.	Low pop noise. Duration until mute function is turned on/off is long.		
C5	3900 μF	V _{CC1} , V _{CC2}	Ripple filter	Power supply ripple filtering			
C6	1 μF	AC-GND	Common reference voltage for all input	Pop noise is suppressed when C1: C6 = 1:4. (Note6)			
R1	47kΩ	Mute	To reduce pop noise	High pop noise. Duration until mute function is turned on/off is short.	Low pop noise. Duration until mute function is turned on/off is long.		
R2	2.2kΩ less(Note7)	AC-GND	To reduce pop noise	High pop noise.	Low pop noise.		

Note4: When the unrecommended value is used, please examine it enough by system evaluation.

Note5: The constant of C2 affects the turn on time; thus, it must be determined on a application basis of over the 10uF.

Note6: Since "AC-GND" pin is a common reference voltage for all input, this product needs to set the ratio of an input apacitance (C1) and the AC-GND capacitance (C6) to 1:4.

Note7: Please confirm the No.11: 6-V cruising functionality when the constant of R2 is selected.

7. Standby Switch (pin 4)

The power supply can be turned on or off via pin 4 (Stby). The threshold voltage of pin 4 is set at about 3 VBE (typ.). The power supply current is about 0.01 μ A (typ.) in the standby state.

Stand-by	Power	V _{SB} (V)		
ON	OFF	0 to 0.9		
OFF	ON	2.2 to V_{CC}		



Figure 7-1 Setting Pin 4 High Turns on Power

Check the pop levels when the time constant of pin 4 is changed.

Benefits of the Standby Switch

- (1) V_{CC} can be directly turned on or off by a microcontroller, eliminating the need for a switching relay.
- (2) Since the control current is minuscule, a low-current-rated switching relay can be used.



Figure 7-2 Standby Switch

8. Mute Switch (pin 22)

The audio mute switch is enabled by setting pin 22 Low. R_1 and C_4 determine the time constant of the mute. The time constant affects pop noise generated when power or the mute is turned on or off; thus, it must be determined on a per-application basis.

The value of the external pull-up resistor is determined, based on pop noise value.

For example, when the control voltage is changed from 5 V to 3.3 V, the pull-up resistor should be: 3.3 V/5 V \times 47 k Ω = 31 k Ω



Figure 8-1 Mute Function

Figure 8-2 Mute Attenuation– V_{MUTE} (V)

9. Mute Mode

The mute mode in this product is a mute at standby on/off, an internal mute for low voltage. If the mute is turned off before charging C1 and C4 is finished, pop noise occurs because of input offset. Set "mute-off" with sufficient margin in considering a charge time.

9.1 Low Voltage Mute

Internal mute is turned on automatically when VCC drops below approximately 5.6 V.

9.2 Standby off Mute

Internal mute is turned on when the Standby input is driven Low and kept on until the voltage at the Ripple pin reaches approximately (1/2Vcc - 0.7) V.





10. Detection function (pin25)

10.1 DC Offset Detection

The purpose of the integrated DC offset detector is to avoid an anomalous DC offset on the outputs, produced by the input capacitor due to leakage current or short-circuit.



Figure 10-1 Hardware Output Offset Detection

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10.2 Output Short Detection

In case of shorting output to VCC/GND or over voltage power supplied, NPN transistor is turned on. In case of shorting output to output NPN Tr. is turned on and off in response to the input signal voltage.

10.3 Layer Short Detection

The TB2938HQ may be properly connected to a load such as a $4-\Omega$ speaker, but one of the speaker lines may be shorted to ground through a low-impedance path. The TB2938HQ can detect such a condition.



Figure 10-2 Layer Short

As is the case with output DC offset detection, pin 25 is also activated when there is a short on one of the speaker lines as shown above. The detection impedance is 4.5Ω (typ.).

This feature allows detection of a short-circuit through a low-impedance path other than the speaker impedance. It helps to avoid speaker damage in case of anomalous system conditions and improve system reliability.

11. 6-V Cruising Functionality

The TB2938HQ can continually provide audio output even in the event of an abrupt battery voltage drop as a result of reboot from idling stop mode. To reduce the turn-on pop, it is recommended to use a resistor of 2.2 k Ω or less for Rg, a signal source resistor. Inserting a resistor of (C1 / C6 × Rg) in series with C6 helps to further reduce the pop.

When $Rg > 2.2 k\Omega$, the amount of pop should be carefully verified in the end-use application environment.



Figure11-1 Vicinity of the Input Pins

12. Protection Functions

This product has internal protection circuits such as thermal shut down, over-voltage, out to V_{CC} , out to GND, and out to out short circuit protections.

(1) Thermal shut down

It operates when junction temperature exceeds 150°C (typ.). When it operates, it is protected in the following order.

- 1. An Attenuation of an output starts first and the amount of attenuation also increases according to a temperature rising,
- 2. All outputs become in a mute state, when temperature continues rising in spite of output attenuation.
- 3. Shutdown function starts, when a temperature rise continues though all outputs are in a mute state.

In any case if temperature falls, it will return automatically.

(2) Over-voltage

It operates when voltage exceeding operating range is supplied to VCC pin. If voltage falls, it will return automatically. When it operates, output bias is turned off and an output is intercepted.

(3) Short to VCC, Short to GND, Output to output short

It operates when each pin is in irregular connection. If irregular connection is canceled, it will return automatically.

Short circuit protection can operate for each channel.

When it operates, output bias of corresponding output is turned off and an output is intercepted. Example) If channel 1 output shorts, channel 1 is protected but other channels 2 to 4 are available.

(4) Prevention of speaker damage (in case of a layer short-circuit of the speaker)

When the DC resistance between the OUT+ and OUT- pins falls below 1 Ω , the output current exceeds 4 A. At this time, the protection circuit is activated to limit the current draw into the speaker. This feature prevents the speaker from being damaged, as follows:

< Speaker damaging scenario >

⊥

A DC current of over 4 V is applied to the speaker due to an external circuit failure (Note 8). (Abnormal DC output offset)

The speaker impedance becomes 1 Ω or less due to a layer short.

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A current of over 4 A flows into the speaker, damaging the speaker.



Figure 12-1 Prevention of speaker damage

Note8: An abnormal DC offset voltage is incurred when the input bias to the power IC is lost due to a leakage current from a coupling capacitor at the input or a short-circuit between the IN and adjacent lines.

13. Absolute Maximum Ratings

Characteristics	Condition	Symbol	Rating	Unit		
supply voltage (surge)	max0.2s	V _{CC (surge)}	50	V		
supply voltage (DC)		V _{CC (DC)}	25	V		
supply voltage (operation)		V _{CC (opr)}	18	V		
output current (peak)		I _{O (peak)}	9	А		
power dissipation	(Note9)	PD	125	W		
Operating temperature range		T _{opr}	-40 to 85	°C		
Storage temperature		T _{stg}	-55 to 150	°C		

 $(Ta = 25^{\circ}C \text{ unless otherwise specified})$

Note9: Package thermal resistance Rth(j-t) = $1^{\circ}C/W$ (typ.) (Ta = $25^{\circ}C$, with infinite heat sink)

The absolute maximum ratings of a semiconductor device are a set of specified parameter values, which must not be exceeded during operation, even for an instant.

If any of these rating would be exceeded during operation, the device electrical characteristics may be irreparably altered and the reliability and lifetime of the device can no longer be guaranteed. Moreover, these operations with exceeded ratings may cause break down, damage, and/or degradation to any other equipment. Applications using the device should be designed such that each maximum rating will never be exceeded in any operating conditions.

Before using, creating, and/or producing designs, refer to and comply with the precautions and conditions set forth in this document.

13.1 Power Dissipation



14. Operating Ranges

Characteristics	Symbol	Condition	Min	Тур.	Max	Unit
Supply voltage	V _{CC}	$R_L=4\Omega$	6	-	18	V

15. Electrical Characteristics

	$(V_{CC} = 13.2 V)$	<i>V</i> , f = 1 l	kHz, $R_L = 4 \Omega$, $Gv=26 dB$, $Ta = 2$	5°C unl	ess othe	erwise s	pecified	
Characteristics	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit	
Quiescent supply current	ICCQ	_	$V_{IN} = 0$	_	160	300	mA	
	P _{OUT} MAX (1)		V _{CC} = 15.2 V, max POWER		49			
Output power	P _{OUT} MAX (2)		V _{CC} = 14.4 V, max POWER		44		w	
	P _{OUT} (1)		V _{CC} = 14.4 V, THD = 10%		29		vv	
	P _{OUT} (2)		THD = 10%	21	24			
Total harmonic distortion	THD		P _{OUT} = 5 W		0.01	0.07	%	
Voltage gain	GV		V _{OUT} = 0.775 Vrms	25	26	27	dB	
Channel-to-channel voltage gain	ΔG_V	_	$V_{OUT} = 0.775 Vrms$	-1.0	0	1.0	dB	
Output poise voltage	V _{NO} (1)		$R_g = 0 \ \Omega$, DIN45405		50		μVrms	
Output noise voltage	V _{NO} (2)	_	$R_g = 0 \Omega$, BW = 20 Hz to 20 kHz	_	50	70		
Ripple rejection ratio	R.R.	_		50	65	_	dB	
Crosstalk	C.T.	_	$R_g = 620 \Omega$ $P_{OUT} = 4 W$	_	80	_	dB	
Output offset voltage	VOFFSET		—	-90	0	90	mV	
Input resistance	R _{IN}		—		90		kΩ	
Standby current	I _{SB}		Standby condition, $V4 = 0$, $V22 = 0$		0.01	1	μA	
Standby control voltage	V _{SB} H	_	POWER: ON	2.2	_	V _{CC}	v	
Standby control voltage	V _{SB} L		POWER: OFF	0		0.9	v	
Mute control voltage	V _M H		MUTE: OFF	2.2		Vcc	v	
Mute control voltage	V _M L		MUTE: ON, $R_1 = 47 \text{ k}\Omega$	0	_	0.9	v	
Mute attenuation	ATT M	_	MUTE: ON, DIN_AUDIO $V_{OUT} = 7.75$ Vrms \rightarrow Mute: OFF	85	100	_	dB	
Upper cut-off frequency	F _{th}	—	G _V = 26dB, -3dB	—	300	—	kHz	
DC offset threshold voltage	V _{off-set}	_	$\begin{array}{l} \text{Rpull-up}=10 \text{ k}\Omega, \ \text{+V}=5.0 \text{ V} \\ \text{Out(+)-Out(-)} \end{array}$	±1.0	±1.5	±2.0	V	
Layer short detection impedance	R half-short		Rpull-up = 10 k Ω , +V = 5.0 V channel (+) or (-) shorted to GND, when between R _S impedance output to GND.		4.5		Ω	
Pin 25 saturation voltage (at each detector ON condition)	P25-Sat	—	Rpull-up = 10 k Ω , +V = 5.0 V (pin 25 = low)	_	100	500	mV	

Note10: fRIP Ripple frequence

VRIP Ripple signal voltage (AC fluctuations in the power supply)

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16. Test Circuit



Components in the test circuits are only used to obtain and confirm the device characteristics.

17. Characteristic Chart

17.1 Total Harmonic Distortion vs. Output Power







Figure 17-2 Total Harmonic Distortion by Power-supply Voltage ($R_L = 4 \Omega$)

17.2 Various Frequency Characteristics



Figure 17-3 Frequency Characteristics of Total Harmonic Distortion



Figure 17-4 Frequency Characteristics of Voltage Gain and Mute Attenuation









17.3 Output Power Characteristics to Input Voltage



17.4 Power Dissipation vs. Output Power



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17.5 Other Characteristic





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18. Package Dimensions

HZIP25-P-1.00F

Unit: mm



Weight: 7.7(typ.)

About solderability, following conditions were confirmed.

(1) Use of Sn-37Pb solder Bath

- solder bath temperature = 230°C
- dipping time = 5 seconds
- the number of times = once
- use of R-type flux
- (2) Use of Sn-3.0Ag-0.5Cu solder Bath
 - solder bath temperature = $245^{\circ}C$
 - dipping time = 5 seconds
 - the number of time = once
 - use of R-type flux

19. 4ch Power IC Evaluation Board

This drawing is a component side, and a schematic diagram of evaluation board "RP-2024 for 4ch power IC using HZIP25-P-1.00F (SPP25), a solder side.

Note: This board can be shared with some products.

Please confirm external parts of the evaluated product beforehand when you unite the evaluation board.

• Component side



Figure 19-1 Pattern of Evaluation Board (component side)

• Solder side



Figure 19-2 Pattern of Evaluation Board (solder side)

20. Attention in Use

- Use an appropriate power supply fuse to ensure that a large current does not continuously flow in case of
 over current and/or IC failure. The IC will fully break down when used under conditions that exceed its
 absolute maximum ratings, when the wiring is routed improperly or when an abnormal pulse noise occurs
 from the wiring or load, causing a large current to continuously flow and the breakdown can lead smoke
 or ignition. To minimize the effects of the flow of a large current in case of breakdown, appropriate
 settings, such as fuse capacity, fusing time and insertion circuit location, are required.
- If your design includes an inductive load such as a motor coil, incorporate a protection circuit into the
 design to prevent device malfunction or breakdown caused by the current resulting from the inrush
 current at power ON or the negative current resulting from the back electromotive force at power OFF. For
 details on how to connect a protection circuit such as a current limiting resistor or back electromotive
 force adsorption diode, refer to individual IC datasheets or the IC databook. IC breakdown may cause
 injury, smoke or ignition.
- Use a stable power supply with ICs with built-in protection functions. If the power supply is unstable, the protection function may not operate, causing IC breakdown. IC breakdown may cause injury, smoke or ignition.
- Carefully select external components (such as inputs and negative feedback capacitors) and load components (such as speakers), for example, power amp and regulator. If there is a large amount of leakage current such as input or negative feedback condenser, the IC output DC voltage will increase. If this output voltage is connected to a speaker with low input withstand voltage, overcurrent or IC failure can cause smoke or ignition. (The over current can cause smoke or ignition from the IC itself.) In particular, please pay attention when using a Bridge Tied Load (BTL) connection type IC that inputs output DC voltage to a speaker directly.
- Over current Protection Circuit

Over current protection circuits (referred to as current limiter circuits) do not necessarily protect ICs under all circumstances. If the Over current protection circuits operate against the over current, clear the over current status immediately. Depending on the method of use and usage conditions, such as exceeding absolute maximum ratings can cause the over current protection circuit to not operate properly or IC breakdown before operation. In addition, depending on the method of use and usage conditions, if over current continues to flow for a long time after operation, the IC may generate heat resulting in breakdown.

Thermal Shutdown Circuit

Thermal shutdown circuits do not necessarily protect ICs under all circumstances. If the Thermal shutdown circuits operate against the over temperature, clear the heat generation status immediately. Depending on the method of use and usage conditions, such as exceeding absolute maximum ratings can cause the thermal shutdown circuit to not operate properly or IC breakdown before operation.

Heat Radiation Design

When using an IC with large current flow such as power amp, regulator or driver, please design the device so that heat is appropriately radiated, not to exceed the specified junction temperature (Tj) at any time and condition. These ICs generate heat even during normal use. An inadequate IC heat radiation design can lead to decrease in IC life, deterioration of IC characteristics or IC breakdown. In addition, please design the device taking into considerate the effect of IC heat radiation with peripheral components.

Installation to Heat Sink

Please install the power IC to the heat sink not to apply excessive mechanical stress to the IC. Excessive mechanical stress can lead to package cracks, resulting in a reduction in reliability or breakdown of internal IC chip. In addition, depending on the IC, the use of silicon rubber may be prohibited. Check whether the use of silicon rubber is prohibited for the IC you intend to use, or not. For details of power IC heat radiation design and heat sink installation, refer to individual technical datasheets or IC databooks.

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